

MU2646, MU2647

SILICON UNIJUNCTION TRANSISTOR

FEATURES:

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number
- Available Non-RoHS (standard) or RoHS compliant (add PBF suffix)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power dissipation ⁽¹⁾	P_D	300	mW
RMS emitter current	$I_{E(RMS)}$	50	mA
Peak pulse emitter current ⁽²⁾	I_E	2	Amps
Emitter reverse voltage	V_{B2E}	30	Volts
Interbase voltage	V_{B2B1}	35	Volts
Operating junction temperature range	T_J	-65 to 125	°C
Storage temperature range	T_{stg}	-65 to 150	°C

Note 1: Derate 3mW/°C increase in ambient temperature. The total power dissipation must be limited by the external circuitry.

Note 2: Capacitor discharge – 10μF or less, 30 volts or less.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter		Symbol	Min	Typ	Max	Unit
Intrinsic standoff ratio ($V_{B2B1} = 10V$) ⁽¹⁾	MU2646 MU2647	η	0.56 0.68	- -	0.75 0.82	-
Interbase resistance ($V_{B2B1} = 3V$, $I_E = 0$)		r_{BB}	4.7	7	9.1	kohms
Interbase resistance temperature coefficient ($V_{B2B1} = 3V$, $I_E = 0$, $T_A = -55^\circ$ to 125°C)		αr_{BB}	0.1	-	0.9	%/°C
Emitter saturation voltage ($V_{B2B1} = 10V$, $I_E = 50\text{mA}$) ⁽²⁾		$V_{EB1(sat)}$	-	3.5	-	Volts
Modulated interbase current ($V_{B2B1} = 10V$, $I_E = 50\text{mA}$)		$I_{B2(mod)}$	-	15	-	mA
Emitter reverse current ($V_{B2E} = 30V$, $I_{B1} = 0$)	MU2646 MU2647	I_{EB20}	- -	0.005 0.005	12 0.2	μA
Peak point emitter current ($V_{B2B1} = 25V$)	MU2646 MU2647	I_P	- -	1 1	5 2	μA
Valley point current ($V_{B2B1} = 20V$, $R_{B2} = 100\text{ohms}$) ⁽²⁾	MU2646 MU2647	I_V	4 8	6 10	- 18	mA
Base-one peak pulse voltage ⁽³⁾	MU2646 MU2647	V_{OB1}	3 6	5 7	- -	Volts

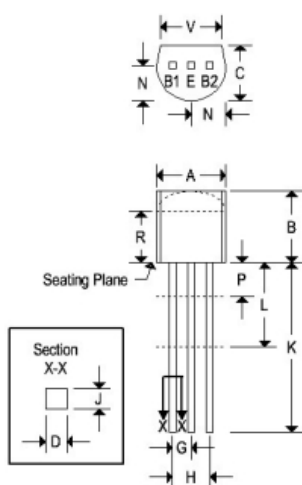
Note 1: Intrinsic standoff ratio: $\eta = (V_P - V_E)/V_{B2B1}$, where V_P = peak point emitter voltage, V_{B2B1} = interbase voltage, V_E = emitter to base one junction diode drop ($\approx 0.45V$ @ $10\mu A$).

Note 2: PW $\approx 300\mu s$, duty cycle $\leq 2\%$ to avoid internal heating due to interbase modulation which may result in erroneous readings

Note 3: Base one peak pulse voltage is used to ensure minimum pulse amplitude for applications in SCR firing circuits and other types of pulse circuits.

MECHANICAL CHARACTERISTICS

Case	TO-92
Marking	Alpha-numeric
Pinout	See below



Dim	TO-92			
	Inches		Millimeters	
	Min	Max	Min	Max
A	0.175	0.205	4.450	5.200
B	0.170	0.210	4.320	5.330
C	0.125	0.165	3.180	4.190
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.150	1.390
H	0.095	0.105	2.420	2.660
J	0.015	0.020	0.390	0.500
K	0.500	-	12.700	-
L	0.250	-	6.350	-
N	0.080	0.105	2.040	2.660
P	-	0.100	-	2.540
R	0.115	-	2.930	-
V	0.135	-	3.430	-

FIGURE 1
UNIUNCTION TRANSISTOR SYMBOL
AND NOMENCLATURE

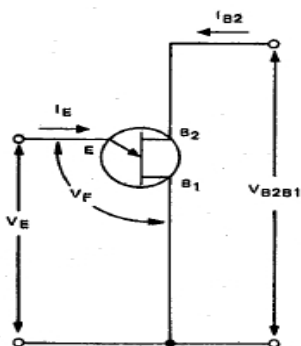


FIGURE 2
STATIC EMITTER CHARACTERISTIC
CURVES
(Exaggerated to Show Details)

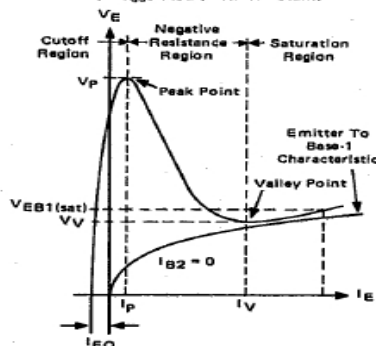


FIGURE 3 - VOB1 TEST CIRCUIT
(Typical Relaxation Oscillator)

